

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	0	chungsu-ock.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 14:34
L3	4	chung-su-ock.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 14:34
L4	81373	MOSFET or "metal oxide semiconductor field effect transistor"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 14:34
L5	1465	(MOSFET or "metal oxide semiconductor field effect transistor") and gate and stack\$4 and plug	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 14:34
L6	1465	(MOSFET or "metal oxide semiconductor field effect transistor") and gate and stack\$4 and plug	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/04 14:38
L9	99	7 and plug	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/04 14:49
L10	395	"hard mask" same stack\$4 same nitride	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/04 15:12
L11	2	"5792687".pn.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/04 15:11
L12	201	"hard mask" and stack\$4 and (SiN or "silicon nitride") and plug and trench	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/04 15:13
L13	314	"hard mask" and stack\$4 and (SiN or "silicon nitride") and plug and (trench or via or contact)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/04 15:13